PROCEEDINGS OF THE INTERNATIONAL CONFERENCE NANOMATERIALS: APPLICATIONS AND PROPERTIES
Vol. **1** No 1, 01PCN32(2pp) (2012)

Picosecond Laser Ablation of Silicon Single Crystal in a Liquid Environment

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(Received 20 June 2012; published online 24 August 2012)

The picosecond Nd:YAG laser at wavelengths of 1064 nm was used to produced the silicon-based nanoparticles in de-ionized water. The main goal of our work presented here was enlight the role of thermal effects on the process of laser ablation of solid target in liquid. To accieve this goal the additional heating of the target surface by continuous laser was applied during the experiment. The shift of nanoparticles size distribution caused by applying of additional continuous laser was reported in this work.

Keywords: Silicon Nanoparticles; Laser Ablation in Liquid; Picosecond Laser.

PACS numbers: 42.55. – f, 61.46.Df

1. INTRODUCTION

Silicon nanoparticles (NPs) find applications and potential applications in numerous fields, such as engineering, biomedicine etc [1, 2]. In the field of theoretical studies, silicon NPs play important role in the study of fundamental quantum effects [3, 4]. The other silicon-based nanoparticles (NPs) attract attention of authors; silica NPs has possible application for the synthesis of functional materials.

A number of methods have been developed for creation of silicon-based nanoparticles, and the one of the most promising is the laser ablation of solid target in liquid (LAL), due it is because relatively simple, fast and "green". Main focus of this work was the analyzing of the role of thermal effect on the LAL process.

2. EXPERIMENTAL METHODS

The silicon targets (square shaped single crystal silicon plates, 15 mm × 15 mm in size) were placed on the bottom of the vessel filled with de-ionized water (DIW). The water layer thickness was kept to about 5mm during the experiments and the volume of the DIW was 3ml. The silicon target was fixed at the position during laser irradiation. The picosecond pulse Nd:YAG laser at wavelengths of 1064 nm was employed. The used laser pulse duration was 150 ps, pulse energy was 70mJ/pulse and the laser exposure time was 10 min. The additional continuous green laser (200 mW) was applied during the LAL process and for 5 minutes immediately prior to application of the pulse laser. The both laser spots, continual and pulsed, were placed at a fixed position in the centre of the silicon target.

The solution obtained by the LAL was dropped onto the silicon substrates and allowed to dry under atmospheric pressure at room temperature. The dried substrates were inspected using a JEOL 840A instrument (SEM) equipped with an INCA Penta FETx3 EDX microanalyzer. For EDX analysis the aluminum substrate was used. All SEM/EDX images were recorded within the 24 hours after the laser irradiation of the targets.

3. RESULTS AND DISCUSSION

The focus of our work presented here was to enlight the role of thermal effects, such as warming of the target, on the LAL process. To acchieve this goal, we provide additional heating of the target surface by applying the additional continuous laser during the experiment. In attempt to minimize the heating of the water layer, we used the green laser.

The use of picosecond pulse duration in our experiment provides that the nonthermal photon-based ablation could be neglected [5].

Figure 1a,b shows the SEM micrograph image of silicon nanoparticles prepared by the picosecond laser ablation in de-ionized water with (a) and without (b) applying the additional continuous laser.

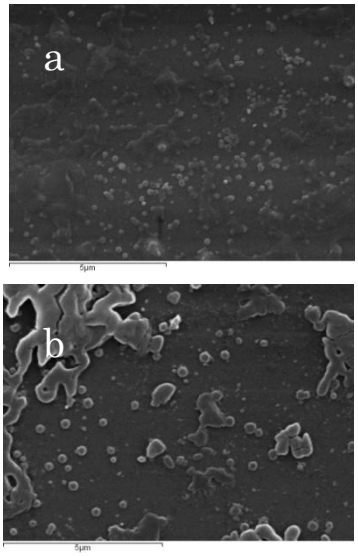

Fig. 1 – SEM micrograph image of silicon nanoparticles prepared by the picosecond laser ablation in de-ionized water (a) with and (b) without applying the additional continuous laser

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The respective distributions obtained by counting approximately 250 particles in SEM image are shown in Fig. 2 a,b respectively. We considered only particles in the 50 nm – 250 nm size range to achieve a size distribution due to the fact that larger ones were uncommon. All particles taken into consideration have a spherical or a nearly spherical shape.

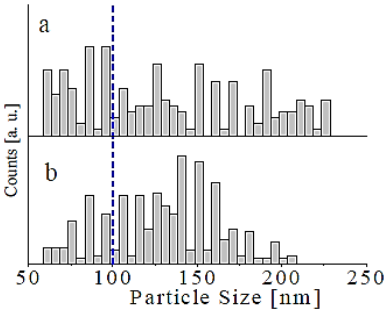

Fig. 2 – Size distributions of silicon nanoparticles prepared by the picosecond laser ablation in de-ionized water (a) with and (b) without applying the additional continuous laser (vertical lines at 100 nm should facilitate comparison).

One could notice from Fig. 2 a,b that applying the continual laser immediately prior and during LAL process changes the NPs size distribution. In the case of applying this laser the region under 100 nm was more populated than in the case when the laser was not applied. Also, the application of the continual laser caused that NPs size distribution was less asymmetric.

The plasma plume could be noticed over the laser spot on the target surface during the LAL process, Therefore, the chemical composition of the produced nanoparticles will be of silicon oxide, which was confirmed by EDX measurements of produced nanoparticles. However, no precise conclusion regards stoichiometry of silicon oxide could be reached.

CONCLUSION

In this paper, we studied the production of silicon-based nanoparticles by irradiating the single crystal silicon target in de-ionized water with Nd:YAG laser at wavelengths of 1064 nm and pulse power of 70 mJ/pulse. To provide additional heating of the target surface the additional continual green laser was applied during and immediately prior the ablation process. The shift of NPs size distribution caused by applying of additional continuous laser was reported.

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